









	<p><b>SI1426DH-T1-E3</b></p>
	<p><b>codice articolo del costruttore:</b> <a href="#">SI1426DH-T1-E3</a></p> <hr/> <p><b>Costruttore / Marca:</b> <a href="#">Vishay / Siliconix</a></p> <hr/> <p><b>Parte della descrizione:</b> MOSFET N-CH 30V 2.8A SC70-6</p> <hr/> <p><b>Schede tecniche:</b>  <a href="#">SI1426DH-T1-E3.pdf</a></p> <hr/> <p><b>Stato di RoHs:</b> Senza piombo / RoHS conforme</p> <hr/> <p><b>Condizione di scorta:</b> New original, 57537 pcs Stock Available.</p> <hr/> <p><b>Nave da:</b> Hong Kong</p> <hr/> <p><b>Modo di spedizione:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

specificazioni

Numero di parte	<a href="#">SI1426DH-T1-E3</a>
fabbricante	<a href="#">Vishay / Siliconix</a>
Descrizione	MOSFET N-CH 30V 2.8A SC70-6
Categoria	<a href="#">Prodotti a semiconduttore discreti &gt; Transistor-FET,</a>
Stato parte	57537 pcs Stock
Serie	TrenchFET®
Tecnologia	MOSFET (Metal Oxide)
temperatura di esercizio	-55°C ~ 150°C (TJ)
Tipo montaggio	Surface Mount
Contenitore / involucro	6-TSSOP, SC-88, SOT-363
Contenitore dispositivo fornitore	SC-70-6 (SOT-363)
Dissipazione di potenza (max)	1W (Ta)
Tipo FET	N-Channel
Caratteristica FET	-
Tensione drain-source (Vdss)	30V
Corrente - Drain continuo (Id) @ 25 ° C	2.8A (Ta)
Rds On (max) a Id, Vgs	75 mOhm @ 3.6A, 10V
Vgs (th) (max) a Id	2.5V @ 250µA
Carica Gate (Qg) (Max) @ Vgs	3nC @ 4.5V
Capacità di ingresso (Ciss) (Max) @ Vds	-
imballaggio	Tape & Reel (TR)









SI1426DH-T1-E3 è nuovo originale in magazzino, ricerca datasheet SI1426DH-T1-E3, PDF, inventario Y-IC.com online, ordine SI1426DH-T1-E3 Vishay / Siliconix con garanzia e garanzia. RFQ SI1426DH-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Potresti essere anche interessato:

 <p><b>SI1427EDH-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 2A SOT-363</p>	 <p><b>SI1426DH-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 2.8A SC70-6</p>	 <p><b>SI1422DH-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 12V 4A SC70-6</p>	 <p><b>SI1427EDH-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 20V 2A SOT-363</p>
 <p><b>SI1426DH-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 2.8A SC-70-6</p>	 <p><b>SI1426DH-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 30V 2.8A SC-70-6</p>	 <p><b>SI1424EDH-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 20V 4A SOT-363</p>	 <p><b>SI1424EDH-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 20V 4A SOT-363</p>

Hot Parts

[Di Più](#)

 SI1410EDH-T1-E3	 SI1410EDH-T1-GE3	 SI1413DH-T1	 SI1413EDH	 SI1413EDH-T1
 SI1413EDH-T1-E3	 SI1413EDH-T1-E3	 SI1413EDH-T1-GE3	 SI1413EDH-T1-GE3	 SI1414DH-T1-GE3
 SI1414DH-T1-GE3	 SI1416EDH-T1-GE3	 SI1416EDH-T1-GE3	 SI1417DH-T1-E3	 SI1417DH-T1-GE3
 SI1417EDH-T1	 SI1417EDH-T1-E3	 SI1417EDH-T1-E3	 SI1417EDH-T1-GE3	 SI1417EDH-T1-GE3
 SI1422DH-T1-GE3	 SI1422DH-T1-GE3	 SI1424EDH-T1-GE3	 SI1424EDH-T1-GE3	 SI1426DH-T1-E3
 SI1426DH-T1-GE3	 SI1426DH-T1-GE3	 SI1427EDH-T1-GE3	 SI1427EDH-T1-GE3	 SI1428EDH-T1-GE3
 SI1428EDH-T1-GE3	 SI1433DH-T1	 SI1433DH-T1-E3	 SI1433DH-T1-E3	 SI1433DH-T1-GE3
 SI1433DH-T1-GE3	 SI1441EDH-T1-GE3	 SI1441EDH-T1-GE3	 SI1442DH-T1-GE3	 SI1442DH-T1-GE3
 SI1443EDH-T1-GE3	 SI1443EDH-T1-GE3	 SI1467DH-T1-GE3	 SI1467DH-T1-GE3	 SI1469DH-T1-GE3
 SI1469DH-T1-GE3	 SI1470DH-M6TR	 SI1470DH-T1-GE3	 SI1470DH-T1-GE3	 SI1471DH-T1

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